



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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- 1N4153UR-1 AVAILABLE IN JAN, JANTX, AND JANTXV
PER MIL-PRF-19500/337
- SWITCHING DIODE
- HERMETICALLY SEALED
- METALLURGICALLY BONDED
- DOUBLE PLUG CONSTRUCTION

1N4153UR-1
CDLL4153

MAXIMUM RATINGS

Junction Temperature: -65°C to +175°C
 Storage Temperature: -65°C to +175°C
 Operating Current: 150 mA @ $T_A = +25^\circ\text{C}$
 Derating: 1.0 mA dc/°C Above $T_A = +25^\circ\text{C}$
 Forward Surge Current: 2A (pk), (tp = 1μs); 0.25A (pk), (tp = 1s)

ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified.

Type	V_{BR}	V_{RWM}	I_{R1}	I_{R2}	C	t_{rr}
	$I_R = 5 \mu\text{A}$		$V_R = 50 \text{ V dc}$ $T_A = 25^\circ\text{C}$	$V_R = 50 \text{ V dc}$ $T_A = 150^\circ\text{C}$	$V_R = 0; f = 1 \text{ Mhz};$	
	V dc	V (pk)	nA dc	μA dc	pF	ns
4153UR-1 CDLL4153	75 75	50 50	50 50	50 50	2.0 2.0	4 4

FORWARD VOLTAGE LIMITS – ALL TYPES

Limits	V_{F1}	V_{F2}	V_{F3}	V_{F4}	V_{F5}	V_{F6}
	$I_F = 100 \mu\text{A dc}$	$I_F = 250 \mu\text{A dc}$	$I_F = 1 \text{ mA dc}$	$I_F = 2 \text{ mA dc}$	$I_F = 10 \text{ mA dc}$	$I_F = 20 \text{ mA dc}$
	V dc	V dc	V dc	V dc	V dc	V dc
minimum	0.49	0.53	0.59	0.62	0.70	0.74
maximum	0.55	0.59	0.67	0.70	0.81	0.88

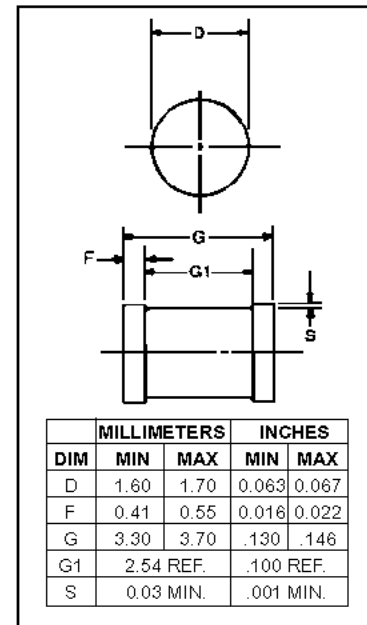


FIGURE 1

DESIGN DATA

CASE: DO-213AA, Hermetically sealed glass case. (MELF, SOD-80; LL34)

LEAD FINISH: Tin / Lead

THERMAL RESISTANCE ($R_{\theta JEC}$):
100 °C/W maximum at L = 0

THERMAL IMPEDANCE: ($Z_{\theta JX}$): 70 °C/W maximum

POLARITY: Cathode end is banded.

MOUNTING SURFACE SELECTION:
The Axial Coefficient of Expansion (COE) of this Device is Approximately +6PPM/°C. The COE of the Mounting Surface System Should Be Selected To Provide A Suitable Match With This Device.



IN4153UR-1 and CDLL4153

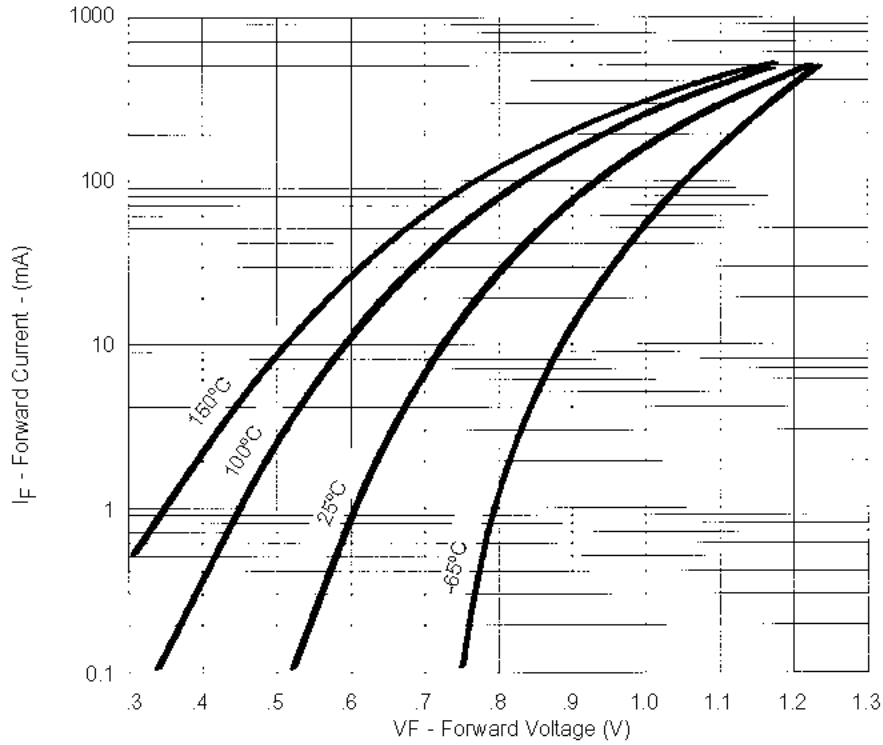
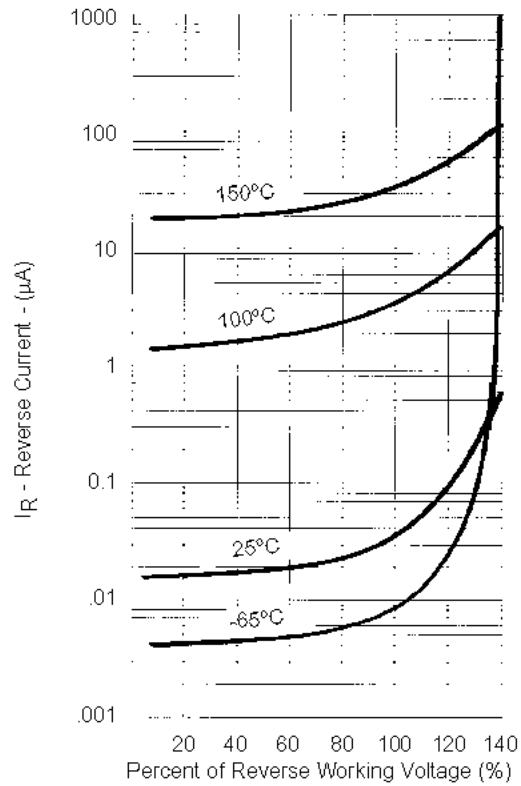


FIGURE 2
Typical Forward Current
vs Forward Voltage



NOTE : All temperatures shown on graphs are junction temperatures

FIGURE 3
Typical Reverse Current
vs Reverse Voltage